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FAIRCHILD

SEMICONDUCTOR

FDS4070N7

40V N-Channel PowerTrench[®] MOSFET

General Description

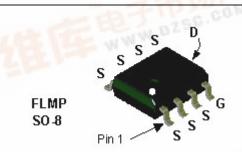
This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for "low side" synchronous rectifier operation, providing an extremely low $R_{DS(ON)}$ in a small package.

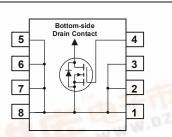
Applications

- Synchronous rectifier
- DC/DC converter

Features

- 15.3 A, 40 V. $R_{DS(ON)}$ = 7 m Ω @ V_{GS} = 10 V
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability
- Fast switching, low gate charge
- FLMP SO-8 package: Enhanced thermal performance in industry-standard package size





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Paramete	er en	Ratings	Units
V _{DSS}	Drain-Source Voltage		40	
V _{GSS}	Gate-Source Voltage		± 20	
I _D	Drain Current – Continuous	(Note 1a)	15.3	А
	- Pulsed		60	- thi
P _D	Maximum Power Dissipation	(Note 1a)	3.0	
T _J , T _{STG}	Operating and Storage Junction	Temperature Range	-55 to +150	
Therma	I Characteristics	-	B F WWW	
	Thermal Resistance, Junction-to-Ambient (Note 1a)			
$R_{\theta JA}$	Thermal Resistance, Junction-to	-Ambient (Note 1a)	40	°C/W
R _{θJA} R _{θJC}	Thermal Resistance, Junction-to Thermal Resistance, Junction-to	· · · · ·	40 0.5	°C/W
$R_{ ext{ heta}JC}$		-Case (Note 1)		°C/W
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction-to e Marking and Orderin	-Case (Note 1)		C/W



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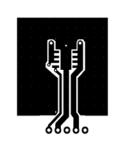
January 2004

Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
•	Durce Avalanche Ratings (Note	2)				
E _{AS}	Drain-Source Avalanche Energy	Single Pulse, V _{DD} =40V, I _D =15.3A			310	mJ
I _{AS}	Drain-Source Avalanche Current				15.3	Α
Off Char	acteristics					
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V$, $I_{D} = 250 \mu A$	40			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C		42		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 32 V$, $V_{GS} = 0 V$			1	μA
I _{GSSF}	Gate–Body Leakage, Forward	$V_{GS} = 20 V, V_{DS} = 0 V$			100	nA
I _{GSSR}	Gate-Body Leakage, Reverse	$V_{GS} = -20 V, V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2	3.9	5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25 °C		-8		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	V_{GS} = 10 V, I_D = 15.3 A V_{GS} = 10 V, I_D =15.3A, T_J =125°C		5 7.5	7 11	mΩ
g _{FS}	Forward Transconductance	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 15.3 \text{ A}$		52		S
Dynamic	c Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 20 V$, $V_{GS} = 0 V$,		2819		pF
Coss	Output Capacitance	f = 1.0 MHz		600		pF
C _{rss}	Reverse Transfer Capacitance			291		pF
Switchin	ng Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 20 V, I_D = 1 A,$		16	29	ns
tr	Turn–On Rise Time	V_{GS} = 10 V, R_{GEN} = 6 Ω		12	22	ns
t _{d(off)}	Turn–Off Delay Time			41	66	ns
t _f	Turn–Off Fall Time			29	46	ns
Qg	Total Gate Charge	$V_{\rm DS} = 20 \text{ V}, I_{\rm D} = 15.3 \text{ A},$		47	67	nC
Q _{gs}	Gate–Source Charge	V _{GS} = 10 V		15		nC
Q _{gd}	Gate–Drain Charge			14		nC

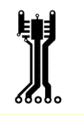
LIECUI	cal Characteristics	$T_A = 25^{\circ}C$ unless otherwise noted		i		i
Symbol	Parameter Test Conditions			Тур	Мах	Units
Drain-S	ource Diode Characteristics a	and Maximum Ratings				
ls	Maximum Continuous Drain-Source	Diode Forward Current			2.5	А
I _S V _{SD}	Maximum Continuous Drain–Source Drain–Source Diode Forward Voltage	Diode Forward Current $V_{GS} = 0 V$, $I_S = 2.5 A$ (Note 2)		0.7	2.5 1.2	A V
-	Drain–Source Diode Forward			0.7		A V nS

Notes:

1. R_{6UA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{8JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



a) 40°C/W when mounted on a 1in² pad of 2 oz copper

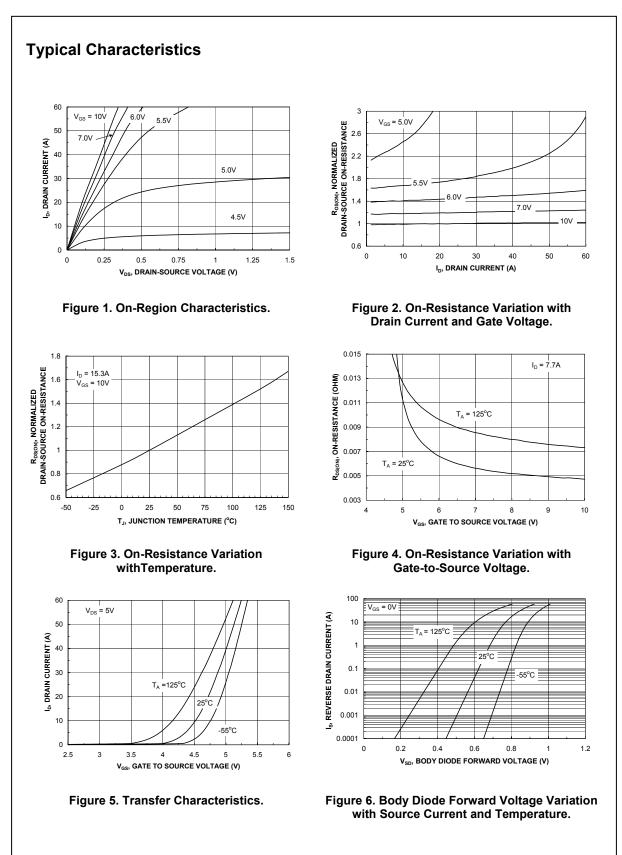


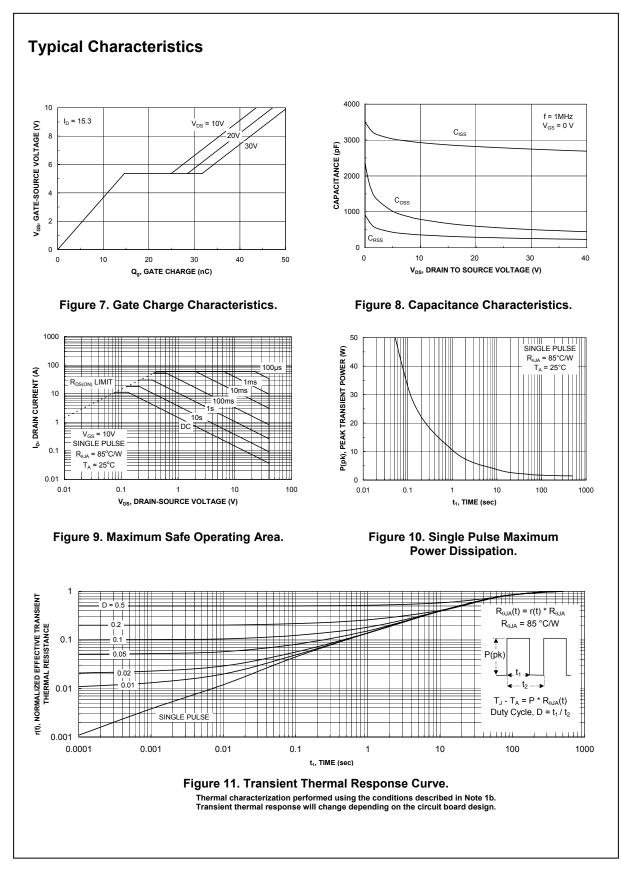
85°C/W when mounted on a minimum pad of 2 oz copper

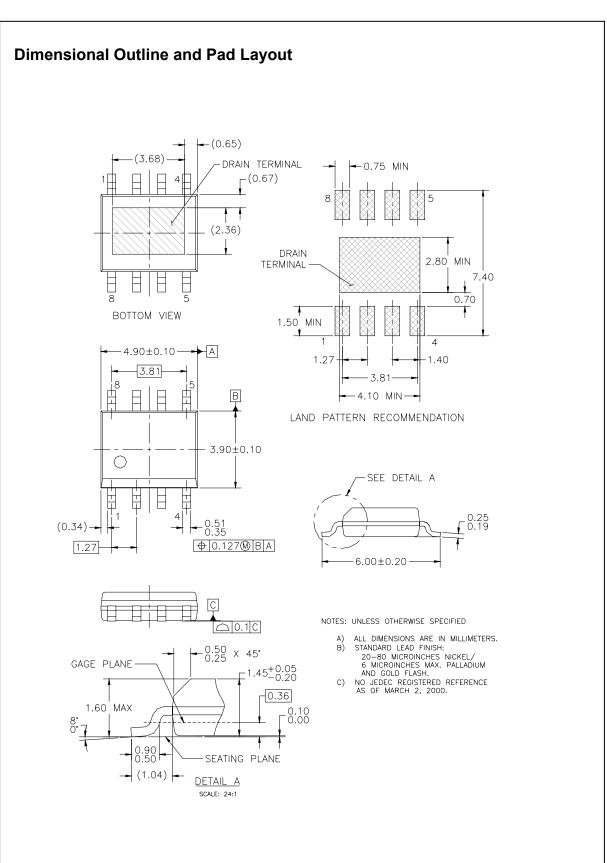
b)

Scale 1 : 1 on letter size pape

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0







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E ² CMOS [™]	HiSeC™	MSXPro™	Quiet Series [™]	TINYOPTO™	
EnSigna™	l²C™	OCX™	RapidConfigure™	TruTranslation™	
FACT™	ImpliedDisconnect™	OCXPro™	RapidConnect™	UHC™	
Across the board	d. Around the world.™	OPTOLOGIC[®]	SILENT SWITCHER®	UltraFET [®]	
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Programmable A		PACMAN™	SPM™		

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E ² CMOS [™]	HiSeC™	MSXPro™	Quiet Series [™]	TINYOPTO™	
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